

Final Product/Process Change Notification Document #:FPCN26212X Issue Date:23 Dec 2024

Title of Change:		Qualification of onsemi ISMF FAB (Malaysia) and ATO site onsemi Leshan (China) for PIN diode housed in X3DFN package.		
Proposed First Ship date:	31 Mar 2025 or earlier	31 Mar 2025 or earlier if approved by customer		
Contact Information:	Contact your local onse	Contact your local onsemi Sales Office		
PCN Samples Contact:	Contact your local onsemi Sales Office. Sample requests are to be submitted no later than 30 days from the date of first notification, Initial PCN or Final PCN, for this change. Samples delivery timing will be subject to request date, sample quantity and special customer packing/label requirements.			
Additional Reliability Data:	Contact your local onsemi Sales Office			
Type of Notification:	This is a Final Product/Process Change Notification (FPCN) sent to customers. FPCNs are issued 90 days prior to implementation of the change. onsemi will consider this change accepted, unless an inquiry is made in writing within 30 days of delivery of this notice. To do so, contact PCN.Support@onsemi.com			
Marking of Parts/ Traceability of Change:	Changed material can be identified by assembly plant code and lot code which follow onsemi marking format.			
Change Category:	Wafer Fab Change, Assembly Change			
Change Sub-Category(s):	Manufacturing Site Transfer, Manufacturing Process Change, Material Change, Shipping/Packaging/Marking			
Sites Affected:				
onsemi Sites		External Foundry/Subcon Sites		
onsemi Leshan, China		None		
onsemi, ISMF Malaysia				
diode devices packaged in the X3DFN packa	ige.	fab (Malaysia) and Assembly and Test Site of onsemi Leshan (China) for PIN ed manufacturing sites for onsemi, certified with IATF16949:2016 and ISO/TS		
16949:2009, respectively.		ze the BOM, aligning it with the existing onsemi diode product family.		

X3DFN package

	From		Го	
Fab Site	JS Foundry, Japan	JS Foundry, Japan	onsemi, ISMF Malaysia	
Backgrind process site	JS Foundry, Japan JS Foundry, Japan onsemi,		onsemi, ISMF Malaysia	
Wafer probe site	JS Foundry, Japan	JS Foundry, Japan	onsemi, ISMF Malaysia	
Wafer front metal	2.5 um Al	2.5 um Al	2um AiSi	
Wafer back metal	8kA Au		11.5kA TiNiVAg	
Assembly and Test Site	onsemi Seremban, Malaysia	onsemi Le	onsemi Leshan, China	
Bond Wire	0.8 mils Au wire	0.8 mil	0.8 mils Cu wire	

onsemi

Final Product/Process Change Notification Document #:FPCN26212X Issue Date:23 Dec 2024

Leadframe	NiPdAuPd		AuNiAg			
Die attach	CDAF515		8008HT			
Mold compound	G760		G750N			
Device Taping		with Dummy pockets		Without	Dummy pockets	
Product Packing		MPQ Quantity: 10,00 ox Container Quantity:			MPQ Quantity: 15,000 Full Box Container Quantity: 150,000	
Product marking change for X3DFN package Image: Comparison of the package X = Specific Device code X = Specific Device code M = Date code M = Date code Reliability Data Summary: QV DEVICE NAME : SNSDP301MX3T5G (ISMF) RMS : S96826 / L101781 PACKAGE : X3DFN						
Test		Specification	c	ondition	Interval	Results
High Temperature	Reverse Bias	JESD22-A108		100% max rated V	1008 hrs	0/231
High Temperature		JESD22-A103		a= 150°C	1008 hrs	0/231
Preconditio	-	J-STD-020 / JESD-A113		e IOL, TC, uHAST, HAST for nount pkgs only	-	0/924
Intermittent Ope	erating Life	MIL-STD-750 (M1037) AEC-Q101		C, delta Tj=100°C /off = 2 min	15,000 cyc	0/231
Temperature		JESD22-A104	Ta= -5	5°C to +150°C	1000 cyc	0/231
Highly Accelerated		JESD22-A110	130°C, 85%	RH, 18.8psig, bias	96 hrs	0/231
Unbiased Highly Acce Test	elerated Stress	JESD22-A118	130°C, 85% RI	H, 18.8psig, unbiased	96 hrs	0/231
Resistance to So	lder Heat	JESD22- B106	Ta = 2	265°C, 10 sec	-	0/30



Final Product/Process Change Notification Document #:FPCN26212X Issue Date:23 Dec 2024

V DEVICE NAME : SNSDP301MX3T5G (JSF) MS : L93349 ACKAGE : X3DFN					
Test	Specification	Condition	Interval	Results	
High Temperature Reverse Bias	JESD22-A108	Ta=150°C, 100% max rated V	1008 hrs	0/231	
High Temperature Storage Life	JESD22-A103	Ta= 150°C	1008 hrs	0/231	
Preconditioning	J-STD-020 / JESD-A113	MSL 1@260°C, Pre IOL, TC, uHAST, HAST for surface mount pkgs only	-	0/924	
Intermittent Operating Life	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C On/off = 2 min	15,000 cyc	0/231	
Temperature Cycling	JESD22-A104	Ta= -55°C to +150°C	1000 cyc	0/231	
Highly Accelerated Stress Test	JESD22-A110	130°C, 85% RH, 18.8psig, bias	96 hrs	0/231	
Unbiased Highly Accelerated Stress Test	JESD22-A118	130°C, 85% RH, 18.8psig, unbiased	96 hrs	0/231	
Resistance to Solder Heat	JESD22- B106	Ta = 265°C, 10 sec	-	0/30	

Electrical Characteristics Summary:

Electrical characteristics are not impacted.

List of Affected Parts:

Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the **PCN Customized Portal**.

Part Number	Qualification Vehicle
NSDP301MX3T5G	SNSDP301MX3T5G